

**Amendments to the Claims:**

The following listing of claims will replace all prior versions, and listings, of claims in the application:

1-14. (Canceled).

15. (Currently Amended) An electroluminescent device, comprising:

a bank defining a pixel;

an anode provided for the pixel;

a light-emitting layer provided in the pixel and above the anode and including at least an organic polymer;

a thin-film layer provided above the light-emitting layer and overlapping the bank layer, the thin-film layer being continuously formed so as to cover a plurality of pixels; and

a cathode provided above the thin-film layer, the cathode overlapping the bank, being continuously formed so as to cover the plurality of the pixels.

16. (Canceled).

17. (Previously Presented) The electroluminescent device according to claim 15, the thin-film layer suppressing current flowing through the light-emitting layer and not contributing to light emission.

18. (Canceled).

19. (Previously Presented) The electroluminescent device according to claim 15, the bank overlapping edges of the anode.

20. (Original) The electroluminescent device according to claim 15, further comprising:

a hole injection layer having electrical conductivity, the thickness thereof being not less than 100 nm, disposed between the light-emitting layer and the anode.

21. (Original) The electroluminescent device according to claim 15, further comprising:

a buffer layer having electrical conductivity, the thickness thereof being not less than 100 nm, disposed between the light-emitting layer and the anode.

22. (Original) The electroluminescent device according to claim 15, the organic polymer including at least one of polyfluorene and a derivative of polyfluorene.

23. (Original) The electroluminescent device according to claim 15, the organic polymer including at least one of poly(p-phenylenevinylene) and a derivative of poly(p-phenylenevinylene).

24. (Original) The electroluminescent device according to claim 15, the degree of polymerization of the organic polymer being at least two.

25. (Original) The electroluminescent device according to claim 15, the light-emitting layer being formed by depositing a plurality of light-emitting material layers.

26. (Original) The electroluminescent device according to claim 15, the light-emitting layer including the organic polymer being formed by a printing method.

27. (Original) The electroluminescent device according to claim 26, the printing method being an ink-jet method.

28. (Currently Amended) An electronic device having an electroluminescent device, the electroluminescent device comprising:

a bank defining a plurality of pixels;

a plurality of anodes, each of the plurality of anodes being provided for each of the plurality of pixels;

a plurality of light-emitting layers, each of the light emitting layers being provided in each of the plurality of pixels and above each of the plurality of anodes and including at least an organic polymer;

a thin-film layer commonly provided above the plurality of light-emitting layers and overlapping the bank layers, the thin-film layer being continuously formed so as to cover the plurality of pixels; and

a cathode provided above the thin-film layer, the cathode overlapping the bank and the bank overlying edges of the plurality of anodes being continuously formed so as to cover the plurality of the pixels.

29. (Canceled).

30. (Previously Presented) The electronic device according to claim 28, the thin-film layer suppressing current flowing through the light-emitting layer and not contributing to light emission.

31. (Canceled).

32. (Previously Presented) The electronic device according to claim 28, the bank overlapping edges of the plurality of anodes.

33. (Previously Presented) The electronic device according to claim 28, further comprising:

a hole injection layer having electrical conductivity, the thickness thereof being not less than 100 nm, disposed between the light-emitting layer and the anode.

34. (Previously Presented) The electronic device according to claim 28, further comprising:

a buffer layer having electrical conductivity, the thickness thereof being not less than 100 nm, disposed between the light-emitting layer and the anode.

35. (Previously Presented) The electronic device according to claim 28, the organic polymer including at least one of polyfluorene and a derivative of polyfluorene.

36. (Previously Presented) The electronic device according to claim 28, the organic polymer including at least one of poly(p-phenylenevinylene) and a derivative of poly(p-phenylenevinylene).

37. (Previously Presented) The electronic device according to claim 28, the degree of polymerization of the organic polymer being at least two.

38. (Previously Presented) The electronic device according to claim 28, the light-emitting layer being formed by depositing a plurality of light-emitting material layers.

39. (Canceled).

40. (Previously Presented) The electronic device according to claim 28, the printing method being an ink-jet method.

41-42. (Canceled).